

NOT RECOMMENDED FOR NEW DESIGN **USE DMP2110U**



DMP2225L

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)}	Package	I _D T _A = +25°C
-20V	110m Ω @ $V_{GS} = -4.5V$	SOT23	-2.6A
-20V	225mΩ @ $V_{GS} = -2.5V$	30123	-2.0A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

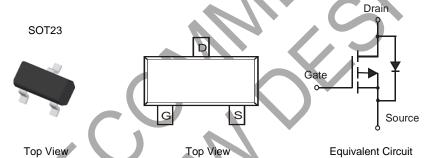
- General Purpose Interfacing Switch
- **Power Management Functions**

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



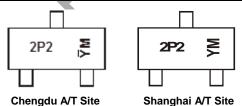
Ordering Information (Note 5)

Part Number	Qualification	Case	Packaging
DMP2225L-7	Standard	SOT23	3000/Tape & Reel
DMP2225LQ-7	Automotive	SOT23	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and 1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



2P2 = Product Type Marking Code

YM = Date Code Marking for SAT (Shanghai Assembly/ Test Site) YM = Date Code Marking for CAT (Chengdu Assembly/ Test Site)

Y or \overline{Y} = Year (ex: F = 2018)

M = Month (ex: 9 = September)

Date Code Key

Year	2008		2009	~		2017	2018	1	2019	2020)	2021
Code	V		W	~		Е	F		G	Н		ı
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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March 2018

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteri	stic		Symbol	Value	Unit
Drain-Source Voltage		V _{DSS}	-20	V	
Gate-Source Voltage		V _{GSS}	±12	V	
Continuous Drain Current (Note 6) Steady $T_A = +25^{\circ}\text{C}$ State $T_A = +70^{\circ}\text{C}$			I _D	-2.6 -2	А
Pulsed Drain Current (Note 7)			I _{DM}	-8	Α

Thermal Characteristics

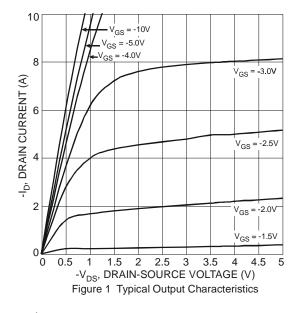
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	P_{D}	1.08	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 6)	R _{0JA}	115	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

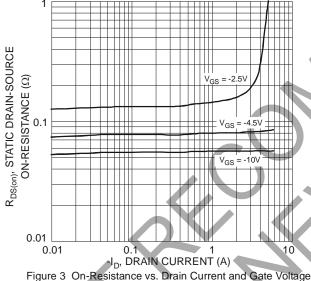
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

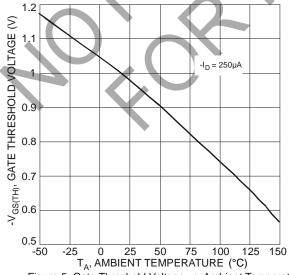
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_		V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	3		-800	nA	$V_{DS} = -20V, V_{GS} = 0V$
On-State Drain Current	I _{D(ON)}	-6	_		Α	$V_{DS} \le -5V$, $V_{GS} = -4.5V$ $V_{DS} \le -5V$, $V_{GS} = -2.5V$
Gate-Source Leakage	I _{GSS}	- 1	-	±80	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)					•	
Gate Threshold Voltage	$V_{GS(TH)}$	-0.45	_	-1.25	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
Static Drain-Source On-Resistance	R _{DS(ON)}		80 165	110 225	mΩ	$V_{GS} = -4.5V, I_D = -2.6A$ $V_{GS} = -2.5V, I_D = -2.0A$
Forward Transfer Admittance	Y _{fs}	_	4	_	S	$V_{DS} = -5V, I_{D} = -2.6A$
Diode Forward Voltage (Note 7)	V _{SD}	7	_	-1.26	V	V _{GS} = 0V, I _S = -2.6A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	_	250	_	pF	101/11/101/
Output Capacitance	Coss	_	88		pF	$V_{DS} = -10V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	58	_	pF	1 = 1.0WI IZ
Gate Resistance	Rg	_	12	16	Ω	$V_{GS} = 0V$, $V_{DS} = 0V$, $f = 1MHz$
Total Gate Charge	Qg	_	4.3	5.3		4.57/.7/
Gate-Source Charge	Qgs	_	0.9	_	nC	$V_{GS} = -4.5V, V_{DS} = -10V,$ $I_{D} = -2.7A$
Gate-Drain Charge	Q_{gd}	_	2.1	_		

Notes:

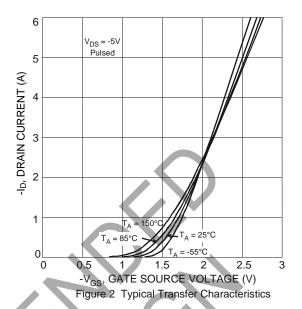
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 7. Repetitive rating, pulse width limited by junction temperature.
 8. Short duration pulse test used to minimize self-heating effect.
 9. Guaranteed by design. Not subject to production testing.

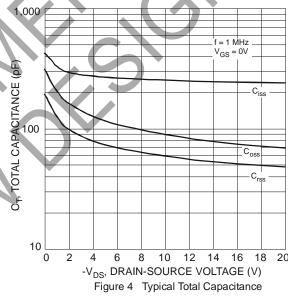












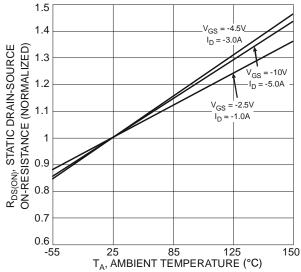


Figure 6 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature



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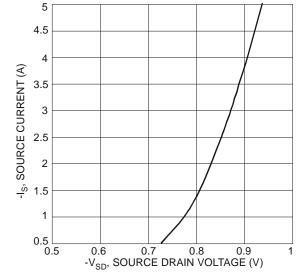
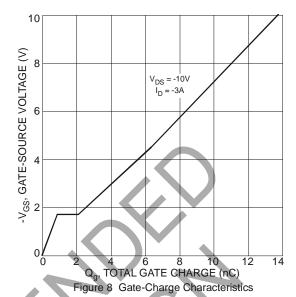
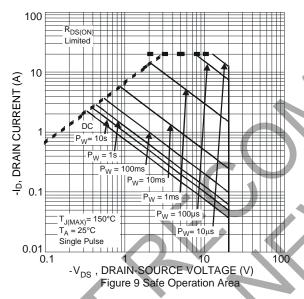
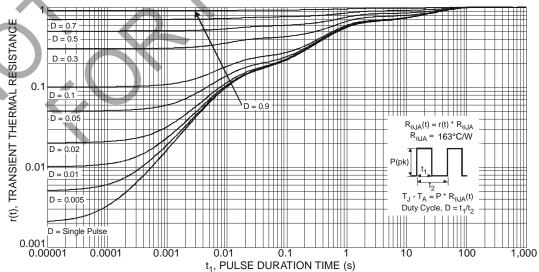


Figure 7 Reverse Drain Current vs. Source-Drain Voltage



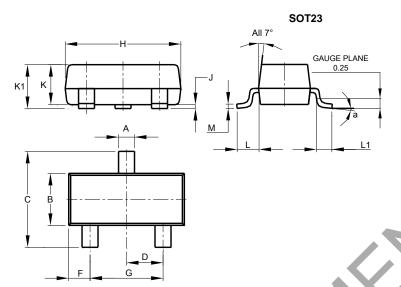




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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

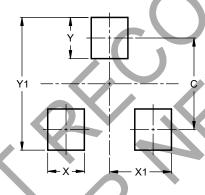


SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
7	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
V1	2.0



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